

#### **Product Description**

Stanford Microdevices' SCA-1 is a high performance Gallium Arsenide MESFET MMIC Amplifier. This device is fabricated using Stanford's reliable 0.5 micron gate MESFET process.

This amplifier is internally matched with typical VSWR of 1.6:1. Its positive gain slope makes it an ideal choice for cascading multiple amplifiers without sacrificing high frequency response.

These unconditionally stable amplifiers provides 10dB of gain and 100mW of 1dB compressed power and require only a single positive voltage supply. Only 2 DC-blocking capacitors and an optional inductor are needed for operation.

This MMIC is an ideal choice for wireless applications such as cellular, PCS, CDPD, wireless data and SONET.

# Output Power vs. Frequency Vd= 5V 22 21 dBm 20 19 18 0.3 1 2 3

#### SCA-1

## 0.3-3 GHz, Cascadable GaAs MMIC Amplifier



#### **Product Features**

• High Output Power: +20dBm P1dB

• Very Flat Gain: +/-0.5dB from 0.3-2.0 GHz

• Cascadable 50 Ohm: 1.6:1 VSWR

Operates From Single Supply

Low Thermal Resistance Package

#### **Applications**

• Cellular, PCS, CDPD, Wireless Data, SONET

#### Electrical Specifications at Ta = 25C

Symbol	Parameters: Test Conditions: V <sub>D</sub> = +5.0V, Z <sub>0</sub> = 50 Ohms		Units	Min.	Тур.	Max.
G <sub>P</sub>	Power Gain	f = 0.3-3.0 GHz	d B	8	10	
G <sub>F</sub>	Gain Flatness Gain Flatness over any 100 MHz band	f = 0.3-2.0 GHz	dB dB		+/- 0.5 +/- 0.1	
P <sub>1dB</sub>	Output Power at 1dB Compression	f = 0.3-3.0 G H z	d B m		+20	
NF	Noise Figure	f = 0.3-3.0 GHz	dB		3.5	
VSWR	Input / Output	f = 0.3-2.0 GHz	-		1.6:1	
IP <sub>3</sub>	Third Order Intercept Point Output Tones @ 0dBm 10 MHz apart	f = 0.3-2.0 GHz	d B m	+28	+32	
T <sub>D</sub>	Group Delay	f = 1.9 GHz	psec		100	
ISOL	Reverse Isolation	f = 0.3-3.0 GHz	dB		14	
I <sub>D</sub>	Device Current	V <sub>D</sub> = +5.0V	m A	60	90	140
dG/dT	Device Gain Temperature Coefficient		dB/degC		-0.0015	

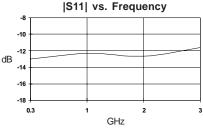
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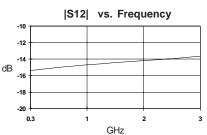
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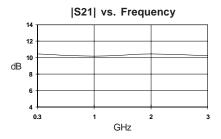


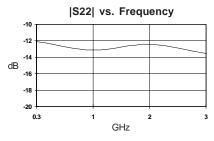
#### SCA-1 0.3-3 GHz Cascadable MMIC Amplifier

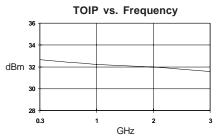
#### Typical Performance at 25° C (Vds = 5.0V, Ids = 90mA)











Typical S-Parameters Vd = 5.0V

Freq GHz	S11	S11 Ang	S21	S21 Ang	S12	S12 Ang	\$22	S22 Ang
.300	.175	-73	2.942	160	.132	-27	.104	-131
.500	.115	-107	3.220	139	.119	-44	.104	136
.750	.075	-134	3.188	114	.113	-59	.114	60
.900	.065	-149	3.116	101	.112	-69	.168	30
1.00	.063	-162	3.077	91	.111	-76	.183	12
1.50	.077	131	3.007	48	.103	-117	.250	-63
2.00	.136	86	3.025	6	.085	-164	.304	-136
2.50	.282	35	3.179	-38	.045	139	.339	135
3.00	.431	-30	3.341	-91	.013	-69	.344	35

(S-Parameters include the effects of two 1.0 mil diameter bond wires, each 20 mils long, connected to the gate and drain pads on the die)



#### **Absolute Maximum Ratings**

Parameter	A b so lute M a x im u m
Device Current	135 m A
Power Dissipation	820 m W
RF Input Power	200 m W
Junction Temperature	+150C
Operating Temperature	-45C to +85C
Storage Temperature	-65C to +150C

#### Notes:

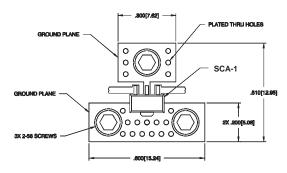
1. Operation of this device above any one of these parameters may cause permanent damage.

#### **Mounting Instructions**

The data shown was taken on a 31 mil thick FR-4 board with 1 ounce of copper on both sides.

The board was mounted to a baseplate with 3 screws as shown. The screws bring the top side copper temperature to the same value as the baseplate.

- 1. Use 1 or 2 ounce copper, if possible.
- 2. Solder the copper pad on the backside of the device package to the ground plane.
- Use a large ground pad area with many plated through-holes as shown.
- 4. If possible, use at least one screw no more than 0.2 inch from the device package to provide a low thermal resistance path to the baseplate of the package.
- 5. Thermal resistance from ground lead to screws is 2 deg. C/W.



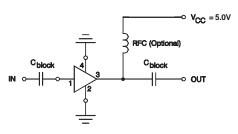
DIMENSIONS ARE IN INCHES [MM]

#### SCA-1 0.3-3 GHz Cascadable MMIC Amplifier

### MTTF vs. Temperature @ Id =90mA, Vd =5V

Lead Temperature	MTTF (hrs)
+85C	1,000,000
+120C	100,000
+150C	10,000

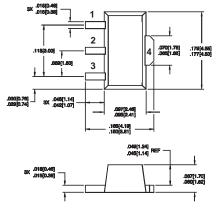
Thermal Resistance (Lead-Junction): 155° C/W



Typical Biasing Configuration

Pin Designation			
1	RF in		
2	GND		
3	RF out and Bias		
4	GND		

#### **Outline Drawing**



DIMENSIONS ARE IN INCHES [MM]

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